Strongly inhibited spontaneous emission of near-IR PbS quantum dots in 3D silicon photonic band gap crystals Andreas S. Schulz^{1,2}, Marek Kozoň^{1,3}, Jurriaan Huskens², G. Julius Vancso⁴, and Willem L. Vos¹

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Introduction

Central in quantum optics and cavity quantum electrodynamics (cQED) \Rightarrow Control properties of matter via the properties of light!

Famous: control radiative rate of elementary quantum emitters, like dye molecules, ions, or quantum dots (QDs) [1] Crucial for *applications*: miniature *lasers* & *light-emitting diodes* [2], *photocatalysis* & photochemistry [3,4], and sensing [5,6]



Optical emitters typically in quantum regime \Rightarrow Emission induced by both radiative reaction ("antenna effect") & by vacuum fluctuations [7]

Vacuum fluctuations: fluctuations of quantized EM-fields (red wavelets), even in free space

Challenge: study **emitters** placed at **well-defined** positions in 3D photonic band gap crystals



- Combined effects captured by local density of radiative states (LDOS) [8]
- LDOS controlled by surrounding emitter by suitably tailored dielectric environment
- Most radical control: 3D photonic band gap: emission strongly inhibited

From Band Gap in Theory to Inhibition in Experiments









(a) Scanning electron micrograph (SEM) of a 3D inverse woodpile photonic crystal (pore radii R=160 nm) made by us at MESA+ (b) Schematic of the unit cell, zooming in one a pore to show how we position QDs by targeted polymer surface-chemistry: ATRP initiator layer (orange), polymer chains forming brushes (green), covalently attached PbS quantum dots (black) on silicon (blue). The positioning was verified by X-ray fluo tomography [9].

0.01 b) 10000 8000 Wavenumber (cm⁻¹)

circles), in suspension (green hexes @1090 nm). Counts plotted vs photon arrival time.

Normalized emission spectra of QDs in several 3D crystals, see central panel. With pore radii R/a=0.19: S9, S8 (a) (b) With pore radii R/a=0.23: S4, S12, S5 Calculated relative DOS for relevant pore radii (connected black symbols) Excellent reproduction between different crystals with same pore radii. Systematic shift of the band gap with varying crystal dimensions

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